MSD42WT1G, NSVMSD42WT1G

NPN High Voltage Transistors

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- These Devices are Pb-Free, Halogen Free and are RoHS Compliant
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	300	V
Collector-Emitter Voltage	V _{(BR)CEO}	300	V
Emitter-Base Voltage	V _{(BR)EBO}	6.0	V
Collector Current - Continuous	Ic	150	mA

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P _D	450	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	274	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS

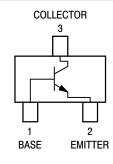
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage $(I_C = 1.0 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	300	-	V
Collector-Base Breakdown Voltage ($I_C = 100 \mu A, I_E = 0$)	V _{(BR)CBO}	300	ı	>
Emitter-Base Breakdown Voltage ($I_E = 100 \mu A, I_E = 0$)	V _{(BR)EBO}	6.0	-	٧
Collector-Base Cutoff Current (V _{CB} = 200 V, I _E = 0)	I _{CBO}	-	0.1	μΑ
Emitter–Base Cutoff Current $(V_{EB} = 6.0 \text{ V}, I_B = 0)$	I _{EBO}	-	0.1	μΑ
DC Current Gain (Note 2) (V _{CE} = 10 V, I _C = 1.0 mA) (V _{CE} = 10 V, I _C = 30 mA)	h _{FE1}	25 40	- -	-
Collector-Emitter Saturation Voltage (Note 2) (I _C = 20 mA, I _B = 2.0 mA)	V _{CE(sat)}	-	0.5	V

- 1. FR-4 @ 10 mm², 1 oz. Copper traces.
- 2. Pulse Test: Pulse Width \leq 300 µs, D.C. \leq 2%.



ON Semiconductor®

http://onsemi.com





SC-70 (SOT-323) CASE 419 STYLE 3

MARKING DIAGRAM



1D = Specific Device Code

M = Date Code

= Pb-Free Package

ORDERING INFORMATION

(Note: Microdot may be in either location)

Device	Package	Shipping [†]
MSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel
NSVMSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSD42WT1G, NSVMSD42WT1G

TYPICAL CHARACTERISTICS

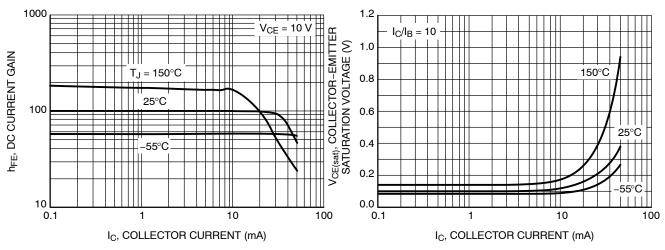


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

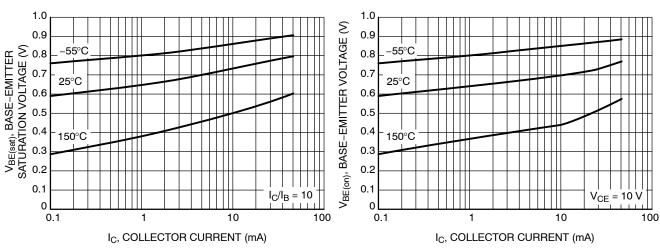


Figure 3. Base-Emitter Saturation Voltage vs.
Collector Current

Figure 4. Base–Emitter On Voltage vs.
Collector Current

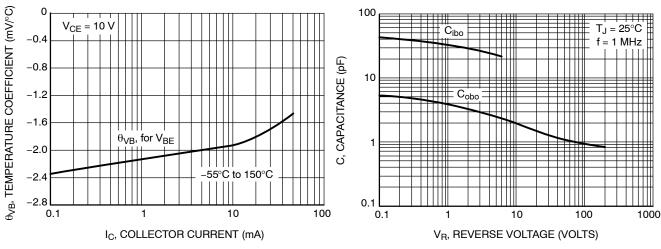
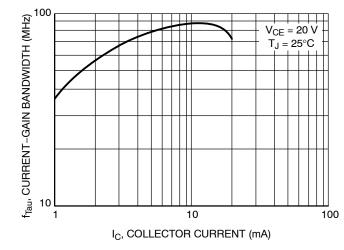


Figure 5. Base–Emitter Temperature Coefficient

Figure 6. Capacitance

MSD42WT1G, NSVMSD42WT1G

TYPICAL CHARACTERISTICS



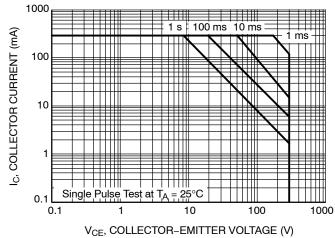
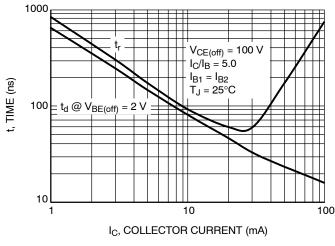


Figure 7. Current-Gain — Bandwidth Product

Figure 8. Safe Operating Area



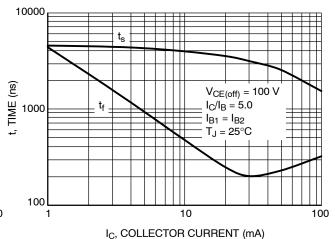


Figure 9. Turn-On Time

Figure 10. Turn-Off Time





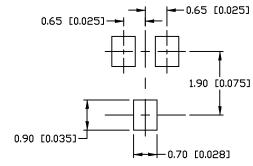
SC-70 (SOT-323) CASE 419 ISSUE P

DATE 07 OCT 2021

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	MILLIMETERS				INCHES	
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.70 REF		0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC				0.026 BS	C
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095
E e e1 L	1.15 1.20 0.20	1.24 1.30 0.65 BS0 0.38	1.35 1.40 0.56	0.045 0.047 0.008	0.049 0.051 0.026 BS 0.015	0.0 0.0 C



For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

TOP VIEW SIDE VIEW END VIEW

GENERIC MARKING DIAGRAM



XX = Specific Device Code

M = Date Code

■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:
PIN 1. EMITTER	PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	2. CATHODE
3. COLLECTOR	3. COLLECTOR	3. DRAIN	3. CATHODE-ANODE	3. ANODE-CATHODE	3. CATHODE

DOCUMENT NUMBER:	98ASB42819B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-70 (SOT-323)		PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative